

Microscopic mechanism for the unusual antiferromagnetic order and the pressure-induced transition to ferromagnetism in USb₂

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Uranium dipnictide USb₂ reflects enigmatic properties posing a substantial challenge for a microscopic modeling. Among others, it develops a nonstandard antiferromagnetic order of a $\uparrow\downarrow\uparrow$ -type along [001] crystallographic direction, and under pressure it undergoes transition to the ferromagnetic phase. Here we propose a minimal low-energy model of USb₂ which, as we demonstrate at the mean-field level, accommodates physical mechanism for mentioned observations. Relying on the obtained results we also comment on the features of magnetism observed in other U-based compounds: UAs₂, UBi₂, UAsSe, URh_xIr_{1-x}Ge and UGe₂.

I. INTRODUCTION

Compounds with active f -electron degrees of freedom host a wealth of diverse unconventional phases of matter. These encompass unconventional superconductivity^{1,2}, magnetism³, and many-body, also possibly topologically nontrivial⁴⁻⁶, insulating and metallic states^{7,8}. However, small energy scales associated with specific features of the electronic structure near Fermi level of f -electron materials substantially limit the effectiveness of many experimental techniques probing the character of emergent orders.

In this light, among various f -electron compounds, USb₂ stands out with the relatively accurately studied electronic structure. There exists a wealth of observations made for this material with a broad spectrum of experimental techniques including: photoemission⁹⁻¹³, Mössbauer¹⁴ and hard X-ray¹¹ spectroscopies as well as neutron diffraction¹⁵, de Haas - van Alphen oscillations^{16,17}, nuclear magnetic resonance^{18,19} and very recent magnetization, magnetostriction and magnetotransport measurements under extreme conditions of high fields²⁰ and strong pressures²¹.

In spite of thorough experimental examination of USb₂, faithful theoretical understanding of some of its characteristics is up to the present day offered only by *ab-initio* studies²². These, however, allow only for a limited insight into physical mechanisms responsible for the specific behavior of a material. In particular, the origin of the nonstandard $\uparrow\downarrow\uparrow$ antiferromagnetic order of spins at uranium atoms in USb₂ along the [001] crystallographic direction^{15,19} (cf. Fig. 1) remains enigmatic. Additionally, very recent experiment on this compound²¹ has suggested a pressure-induced onset of the ferromagnetic phase which calls for a theoretical clarification.

In the present work, motivated by these findings, we develop a low-energy microscopic model rationalizing the unusual antiferromagnetism^{15,19} and the pressure-induced transition to ferromagnetism²¹ in USb₂. Re-

lying on the obtained results we also address properties of magnetic states observed in other U-based compounds: isostructural to USb₂ UAs₂ and UBi₂^{16,17,22,23}, UAsSe²⁴⁻²⁶ and URh_xIr_{1-x}Ge²⁷. Moreover, we provide arguments that ferromagnetism in pressurized USb₂ has the same character as ferromagnetism²⁸⁻³⁰ in the famous spin-triplet superconductor UGe₂³¹. The raised analogy between UGe₂ and USb₂ opens up an intriguing possi-

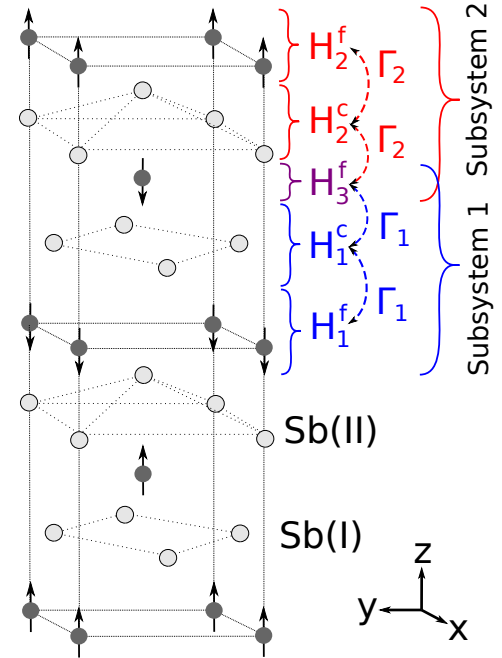


FIG. 1: Schematic picture of the magnetic unit cell of USb₂ with marked orientations of spins at uranium atoms (dark gray color). Inequivalent ligand sites (light gray color) are marked as Sb(I) and Sb(II)^{11,19}. The curly brackets underline assignments of various terms in Eq. (1) for a description of a USb₂ film (parallel to xy -plane) of thickness corresponding to the height of the elementary cell.

bility that USb₂ under pressure may also develop triplet superconductivity in yet unexplored regime of temperature below 2K²¹.

II. MODEL

USb₂ is an antiferromagnet with Néel temperature, $T_N \simeq 200\text{K}$ ⁹ characterized with moderately renormalized effective masses $m^*/m_0 \lesssim 8.33$ ^{16,17}. Both, quantum oscillations measurements^{16,17} and *ab-initio* calculations²² suggest predominantly two dimensional character of the Fermi surface with a weak dispersion along z -direction (cf. Fig.1). Moreover, the low-energy band structure of USb₂ is determined²² as mostly composed of $5f$ uranium orbitals hybridized to these of the ligand. Such scenario has been also indicated in photoemission spectroscopy measurements⁹⁻¹³.

These properties together with the initially localized nature of f -states, indicated by a spatial separation of U-atoms larger than 4\AA , advocate the effective description of USb₂ within the usual Anderson lattice scenario³². Nonetheless, such a description is clearly insufficient in the light of the observation of the unusual $\uparrow\downarrow\downarrow\uparrow$ antiferromagnetic order of spins at uranium atoms along the z -direction¹⁵, as well as a presence of different core levels corresponding to crystallographically inequivalent ligand sites Sb(I) and Sb(II)^{11,18,19} (cf. Fig. 1). Therefore, in the following considerations we account for more specific details of the electronic structure of USb₂.

First, we take advantage of a quasi two dimensional character of USb₂^{16,17,22} and consider only a film of the material (parallel to xy -plane) of a minimal thickness allowing for a description of the unusual order along z -axis. We choose thickness corresponding to the height of the elementary cell, i.e., including three neighboring xy -planes of uranium atoms and antimony in between. Within such a probe of USb₂ structure we aim to validate that any three consecutive xy -planes of uranium atoms develop $[\text{U}(\sigma)\text{Sb}(\text{I})\text{U}(\sigma)\text{Sb}(\text{II})\text{U}(\bar{\sigma})]$ sequence along z -axis, where $\sigma \in \{\uparrow, \downarrow\}$. Here we marked particular positions of inequivalent ligand sites in between σ -polarized layers of U atoms. This conclusion would demonstrate that the polarizations of the neighboring uranium planes with Sb(I) sites in between align ferromagnetically, whereas with Sb(II) sites antiferromagnetically. Thus it would provide a direct rationalization of the emerging magnetism in USb₂.

We describe layers of uranium atoms with Hamiltonians $H_{\alpha \in \{1,2,3\}}^f$, whereas two systems of the conduction electrons corresponding to inequivalent sites of ligand with $H_{\alpha \in \{1,2\}}^c$. Assignment of these partial Hamiltonians to particular systems of atoms is pictorially presented over the height of the single unit cell in Fig. 1. Due to the weak dispersion along z -axis we assume coupling only between the nearest systems of orbitals of uranium and antimony, i.e. describing hybridization. Precisely, we consider coupling of H_1^c to H_1^f and H_3^f through operator

Γ_1 , and analogically of H_2^c to H_2^f and H_3^f through operator Γ_2 (cf. Fig. 1). Then, the full Hamiltonian for an isolated film of USb₂ reads

$$\mathcal{H} = (H_1^c + H_1^f + \Gamma_1) + H_3^f + (H_2^c + H_2^f + \Gamma_2). \quad (1)$$

We propose \mathcal{H} to be a purely two dimensional model. Therefore, the properties along z -direction are solely coded in the indices of operators in (1) referring to the vertical arrangement of considered systems of atoms in accordance with Fig. 1. We emphasize with brackets in Eq. (1) emerging picture of two semi-independent subsystems coupled only through sharing a single layer of uranium atoms (H_3^f). Hereafter, we use a convention that H_3^f and all operators with index $\alpha = 1$ determine the subsystem 1 and the same H_3^f and operators with index $\alpha = 2$ constitute the subsystem 2 (cf. Fig. 1).

First we formulate partial Hamiltonians for electrons at uranium layers. These, according to the *ab initio* calculations²², provide contribution to the low-energy band structure predominantly of $5f$ orbital character. All f -states, due to the large separation between uranium atoms, initially occupy the same atomic energy level ϵ_f . For the reason that any two neighboring layers of uranium atoms form a bipartite square lattice in xy -coordinates, we may propose

$$H_{\alpha \in \{1,2,3\}}^f = \epsilon_f \sum_{\mathbf{i} \in \beta, \sigma} n_{\alpha; \mathbf{i}\sigma}^f + U \sum_{\mathbf{i} \in \beta} n_{\alpha; \mathbf{i}\uparrow}^f n_{\alpha; \mathbf{i}\downarrow}^f, \quad (2)$$

where lattice summation runs over sublattice, $\beta = \text{A}$ for $\alpha = 1, 2$ and $\beta = \text{B}$ for $\alpha = 3$, and $n_{\alpha; \mathbf{i}\sigma}^f \equiv f_{\alpha; \mathbf{i}\sigma}^\dagger f_{\alpha; \mathbf{i}\sigma}$ is the number operator of f -electrons in α -layer of uranium atoms. We account for many-body onsite interaction with amplitude U to account for the strongly correlated nature of f -states. On the other hand, to underline the prevailing importance of this interaction we neglect orbital degeneracy of $5f$ -shell and thus many-body effects such as the Hund's coupling.

In turn, conduction electrons, described with $H_{\alpha \in \{1,2\}}^c$, form bands. For simplicity, we shall assume existence of only two bands in the vicinity of the Fermi level, each generated either from orbitals at Sb(I) (H_1^c) or Sb(II) (H_2^c) sites. Relying on experimental observations¹¹ we account for the shift to the higher energy of the center of Sb(I)-band with respect to this of Sb(II)-band. On the other hand, we shall disregard other possible differences between bands, e.g. in their shape which should play a minor role due to the strong mixing between f and conduction states. For simplicity we generate both bands with the nearest neighbor hopping with the amplitude t on a square lattice,

$$H_{\alpha \in \{1,2\}}^c = -t \sum_{\langle \mathbf{ij} \rangle \sigma} c_{\alpha; \mathbf{i}\sigma}^\dagger c_{\alpha; \mathbf{j}\sigma} + \delta_{\alpha,1} \Delta \sum_{\mathbf{i}\sigma} n_{\alpha; \mathbf{i}\sigma}^c, \quad (3)$$

where $n_{\mathbf{i}\sigma}^c \equiv c_{\mathbf{i}\sigma}^\dagger c_{\mathbf{i}\sigma}$ is the number operator for conduction (c -) electrons, and $\Delta > 0$ is a relative shift between conduction bands.

The remaining, yet unspecified, ingredients of the full Hamiltonian \mathcal{H} (1), are the hybridization operators $\Gamma_{\alpha \in \{1,2\}}$. Due to inequivalent crystallographic positions of Sb(I) and Sb(II) sites in principle hybridization functions may differ with a shape or an amplitude. However, for the present purposes it is enough to assume both operators $\Gamma_{\alpha \in \{1,2\}}$ to describe identical onsite hybridization

$$\Gamma_{\alpha \in \{1,2\}} = V \left[\sum_{i \in A, \sigma} f_{\alpha; i\sigma}^\dagger c_{\alpha; i\sigma} + \sum_{i \in B, \sigma} f_{3; i\sigma}^\dagger c_{\alpha; i\sigma} \right] + \text{H.c.} \quad (4)$$

Having determined form of all terms in the model (1), we may conclude that the proposed earlier two semi-independent subsystems are two Anderson lattices sharing one of the sublattices of f -orbitals (here B). Until now the only apparent difference between both subsystems is the relative shift (Δ) between the centers of the conduction bands, supported by experimental observations of different core levels corresponding to crystallographically inequivalent ligand sites Sb(I) and Sb(II)^{11,18,19} (cf. Fig. 1). However, in a consequence of a common chemical potential in both subsystems, a total number of electrons in each of them ($n_{\alpha \in \{1,2\}}^t$) is different in favor of the subsystem 2 ($n_2^t > n_1^t$). Namely, although f -electron number in each of the subsystems is the same, the conduction band associated with the subsystem 2 due to the lower position of its bottom accommodates more electrons. We shall demonstrate that the presence of mentioned differences between subsystems (shift between conduction bands and filling difference) is a sufficient condition to account for the nonstandard magnetic properties of USb₂.

Coupling between subsystems is introduced solely via sharing one of the f -electron sublattice (cf. Fig. 1). Such circumstance indicates that both subsystems may be treated independently as long as f electron number per spin at sublattice B is the same for both of them. In

result we shall consider magnetic properties of each of the subsystems separately with the following Hamiltonians

$$\begin{aligned} H_{\alpha \in \{1,2\}}^* &= H_\alpha^c + H_\alpha^f + \Gamma_\alpha + H_3^f \\ &= -t \sum_{\langle ij \rangle, \sigma} c_{i\sigma}^\dagger c_{j\sigma} + \delta_{\alpha 1} \Delta \sum_{i\sigma} n_{i\sigma}^c + V \sum_{i\sigma} (f_{i\sigma}^\dagger c_{i\sigma} + \text{H.c.}) \\ &\quad + \epsilon_f \sum_{i,\sigma} n_{i\sigma}^f + U \sum_i n_{i\uparrow}^f n_{i\downarrow}^f - \mu_\alpha \sum_{i,\sigma} (n_{i\sigma}^f + n_{i\sigma}^c). \end{aligned} \quad (5)$$

Coupling between subsystems is simply reestablished by a matching of the average number of f -electrons per spin at the sublattice B resulting from consideration of H_1^* and H_2^* separately.

III. APPLICABILITY OF THE MODEL TO USb₂

A. Renormalized mean-field solution

We approach Hamiltonian (5) in a mean-field manner accounting for antiferro- and ferro-magnetic solutions. Antiferromagnetic state is characterized with a spatial modulation of the number of electrons per spin $n_{i\sigma} = \frac{1}{2}(n^t + \sigma m_{AF} e^{i\mathbf{Q}\mathbf{R}_i})$ with $\sigma \equiv \{+, -\}$ for spin $\{\uparrow, \downarrow\}$, where $\mathbf{Q} = (\pi, \pi)$ is the usual ordering vector and m_{AF} staggered magnetization. In turn, the ferromagnetic state is characterized with $n_{i\sigma} = \frac{1}{2}(n^t + \sigma m_{FM})$ where m_{FM} is uniform spin polarization. For actual calculations (at zero temperature) we use the Gutzwiller approximation combined with a self-consistent optimization of the Slater determinant³³⁻³⁷, equivalent to slave-boson technique³⁸. Details of the method for the consideration of ferromagnetism are presented in Ref. 28. Therefore, here we present only variational antiferromagnetic Hamiltonian defined in the reduced Brillouin zone (RBZ)

$$H^{AF} = \sum_{\sigma} \int_{\mathbf{k} \in \text{RBZ}} d\mathbf{k} \Psi^\dagger \begin{pmatrix} \epsilon_{\mathbf{k}} - \mu & 0 & \frac{q_{\sigma} + q_{\bar{\sigma}}}{2} V & \frac{q_{\sigma} - q_{\bar{\sigma}}}{2} V \\ 0 & \epsilon_{\mathbf{k} + \mathbf{Q}} - \mu & \frac{q_{\sigma} - q_{\bar{\sigma}}}{2} V & \frac{q_{\sigma} + q_{\bar{\sigma}}}{2} V \\ \frac{q_{\sigma} + q_{\bar{\sigma}}}{2} V & \frac{q_{\sigma} - q_{\bar{\sigma}}}{2} V & \epsilon_f - \mu + \frac{\lambda_{\sigma} + \lambda_{\bar{\sigma}}}{2} & \frac{\lambda_{\sigma} - \lambda_{\bar{\sigma}}}{2} \\ \frac{q_{\sigma} - q_{\bar{\sigma}}}{2} V & \frac{q_{\sigma} + q_{\bar{\sigma}}}{2} V & \frac{\lambda_{\sigma} - \lambda_{\bar{\sigma}}}{2} & \epsilon_f - \mu + \frac{\lambda_{\sigma} + \lambda_{\bar{\sigma}}}{2} \end{pmatrix} \Psi, \quad (6)$$

where $\Psi^\dagger = (c_{\mathbf{k}\sigma}^\dagger, c_{\mathbf{k}+\mathbf{Q}\sigma}^\dagger, f_{\mathbf{k}\sigma}^\dagger, f_{\mathbf{k}+\mathbf{Q}\sigma}^\dagger)$, $\epsilon_{\mathbf{k}}$ is the tight binding spectrum of a conduction band, q_{σ} is the usual Gutzwiller narrowing factor^{28,36}, and

$$\lambda_{\sigma} = \frac{\partial \langle H^* \rangle_G}{\partial \langle n_{\sigma} \rangle_0}. \quad (7)$$

Here $\langle \dots \rangle_0$ denotes an expectation value with the Slater determinant and $\langle \dots \rangle_G$ with the Gutzwiller wave function under the Gutzwiller approximation.

In calculations, we choose hopping of conduction electrons as the energy scale, i.e., $t = 1$. If it is not stated

otherwise remaining microscopic parameters are set to $U = 10$, $V = -0.7$, $\epsilon_f = -2.5$. Large f - f interaction and f -level well below the center of the conduction band are indirectly suggested by the effective quasiparticle mass renormalization in USb₂^{16,17}. On the other hand sizable hybridization has been suggested by the photoemission spectroscopy⁹. The other important parameter, a total number of electrons in both subsystems $n_1^t + n_2^t$ is an arbitrary chosen fitting parameter. The convenient fitting procedure can be established by setting filling in only one of the subsystems (e.g. n_2^t) and deriving $n_1^t + n_2^t$ after-

wards from the matching condition between subsystems.

B. Ambient pressure groundstate

It is a well-established result that if the total number of electrons is close to the half-filling, the Anderson lattice model supports antiferromagnetism^{39–41}. In turn, if the total number of electrons is away from the half-filling it favors ferromagnetism instead^{28,39–44}. Therefore, for the subsystem 2 we set number of electrons per site close to the half-filling, $n_2^t = 1.9$ where indeed antiferromagnetic state is stable against ferromagnetism and paramagnetism and is characterized with f -electron number per site $n_2^f = 0.980$ and staggered f -electron magnetization $m_{f,AF} = 0.973$. Now, parameters characterizing the subsystem 1 ($\Delta > 0$ and $n_1^t < n_2^t$) are determined by reintroducing its coupling to the subsystem 2. Namely, we look for Δ and n_1^t such that the ferromagnetic solution would be characterized with the f -electron number $n_1^f = 0.980$ and uniform f electron magnetization $m_{f,FM} = 0.973$. This procedure yields $n_1^t \simeq 1.7$ and $\Delta \simeq 0.65$. In this case however, ferromagnetism has the lowest energy among considered states. Such result demonstrates that the alternation in positions of centers of conduction bands, associated with Sb(I) and Sb(II) ligand sites is sufficient feature of this material that can be responsible for the particular nonstandard antiferromagnetic order observed in USb₂ at ambient pressure¹⁵.

C. Magnetic groundstate switching under pressure

Now we shall discuss the evolution of the predicted groundstate of USb₂ driven by the change of microscopic parameters associated with the increase of pressure in the considered system. In the Anderson lattice model, impact of pressure is mostly associated with the decreasing ratio U/V or ϵ_f/V ^{28,29,45,46}. In principle a relation of these parameters to the conduction band-width should be also important, and therefore fixed ratio V/t during the evolution with pressure is sometimes considered⁴⁶. Here however, for simplicity, the effect of pressure is modeled by the increase of the hybridization amplitude $|V|$ and the increase of the atomic f -electron level ϵ_f , given that the remaining microscopic parameters do not change. In Fig. 2 we present magnetic phase diagram of the Anderson lattice on the ϵ_f - $|V|$ plane for fixed total number of electron $n^t = 1.9$ corresponding to the initial filling of the subsystem 2. Increase of either $|V|$ or ϵ_f inevitably drives the transition from antiferromagnetism to ferromagnetism. On the other hand, the Anderson lattice for $n^t = 1.7$ corresponding to the initial filling of the subsystem 1, in the range of parameters presented in Fig. 2 orders ferromagnetically. This result explains the transition to the ferromagnetic state observed in USb₂²¹ under applied pressure.

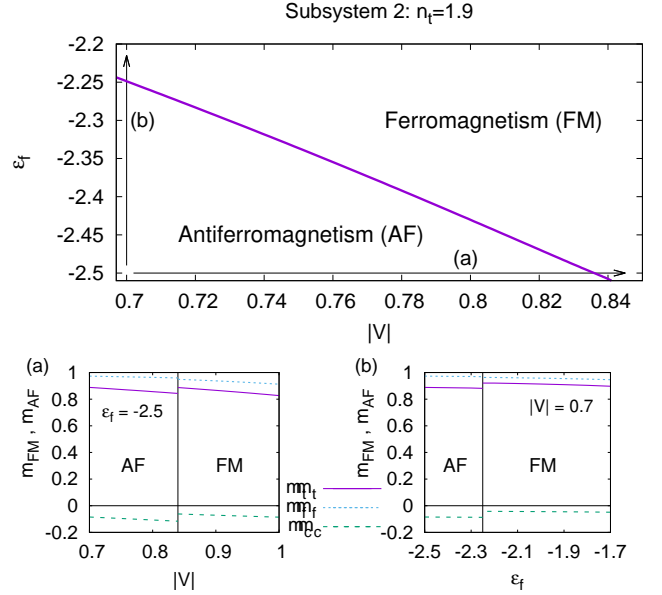


FIG. 2: Phase diagram on ϵ_f - $|V|$ plane resulting from Hamiltonian (5) for electron filling $n^t = 1.9$ and $\Delta = 0$. Total number of electrons as well as parameter's values $\epsilon_f = -2.5$ and $|V| = 0.7$ (left, bottom corner of diagram) refer to the ambient pressure state of the subsystem 2. In panels (a) and (b) there are plotted orbitally resolved magnetization curves (m_c for conduction electrons, m_f for f -electrons and $m_t = m_c + m_f$) across the phase transition along selected, and marked with arrows at the phase diagram, directions.

Here we have assumed that number of electrons is conserved separately in each of the subsystems. Nevertheless, we have also checked that if a difference between fillings is decreasing along any hypothetical line associated here with applied pressure and $\Delta > 0$, reached conclusions are the same.

In order to characterize, at least partially, obtained magnetic groundstate switching from antiferromagnetic to ferromagnetic one in Figs. 2(a-b) we plot total (m_t) as well as orbitally-resolved magnetizations (m_c of conduction electrons, m_f of f -electrons) across such transition for selected directions marked at phase diagram with arrows. It is quite intriguing that although magnetic groundstate switches, absolute value of spin-polarization at single site changes only slightly. We believe that this feature could be verified experimentally. In fact similar behavior, i.e. comparable uniform and staggered magnetizations across phase transition between different magnetic groundstates, has been recently observed in LaCrGe₃^{47,48}.

Further increase of hybridization or raise of f -level in proposed model should drive the transition from ferromagnetic to paramagnetic phase^{28,45} as it is also observed in USb₂ under pressure²¹. However, within the considered here disentangled (5) rather than full model (1), for instance the order of such transition is not resolvable in a sensible manner. Nonetheless, as a consequence of

predicted in a present work itinerant character of ferromagnetism in USb_2 we may safely predict the existence of tricritical wings in this material, semi-universally observed in d - and f -electron^{3,48–50} metallic ferromagnets. These are theoretically supported in the Anderson lattice already at the mean-field level given that the transition to paramagnetism is inherently of the first order^{29,30}. On the other hand, if the transition at the mean-field level would be of the second order, than under the theory of Belitz, Kirkpatrick and Vojta quantum criticality would be avoided⁵¹ and tricritical wings would nevertheless appear⁵².

IV. CORRESPONDENCE OF THE MODEL TO OTHER U-BASED MATERIALS

In the present work we have constructed a microscopic model for magnetism observed in USb_2 . However, there are also other materials that the properties of the proposed model can refer to. These are isostructural to USb_2 UAs_2 and UBi_2 , UAsSe , $\text{URh}_x\text{Ir}_{1-x}\text{Ge}$ and famous spin-triplet superconductor UGe_2 . In this section we shall comment on the magnetic properties of these materials in a context of obtained results.

A. UAs_2 and UBi_2

Isostructural uranium dipnictides UX_2 ($X=\text{Sb,As,Bi}$) share many similarities, starting from (i) antiferromagnetic order at ambient pressure, (ii) quasi-two dimensional, cylindrical Fermi surfaces along $[001]$ direction^{16,17,23}, (iii) strong evidences for the hybridization of $5f$ with conduction electrons^{9,22}, as well as (iv) uranium atom spacing beyond so-called Hill limit. We have found in the literature clear evidences for the different core levels of inequivalent ligand sites only for USb_2 ^{11,18,19}. However, in a following discussion we shall assume that the same scenario applies also to the other members of the series, and thus proposed in a present work model is relevant for their description as well.

In Table I we have gathered selected properties of members of UX_2 series organized with decreasing T_N . Apparently UBi_2 , although it has lowest Néel temperature, is a better antiferromagnet than USb_2 , and is characterized with the larger moment at uranium atoms forming usual sequence of spin polarizations $\uparrow\downarrow\uparrow\downarrow$ along

	T_N (K)	μ_{ord} (μ_B/U)	$[001]$ -seq.	m^*/m_0
UAs_2	273	1.61	$(\uparrow\downarrow\uparrow\uparrow)$	0.33-4.50
USb_2	200	1.88	$(\uparrow\downarrow\uparrow\uparrow)$	1.84-8.33
UBi_2	183	2.1	$(\uparrow\downarrow\uparrow\downarrow)$	4.40-9.20

TABLE I: Differences among UX_2 series in Neel temperature (T_N), ordered moment (μ_{ord}), sequence of polarization of uranium layers along $[001]$ direction and effective mass renormalization (m^*/m_0) as seen by de Haas-van Alphen oscillations.

z -axis. On the other hand, based on the same characteristics UAs_2 seems to be the worst antiferromagnet among UX_2 family.

Increasing effective masses when going from UAs_2 through USb_2 to UBi_2 can point to a possible decrease of the hybridization amplitude³². Such scenario can be indeed realized for UX_2 family because $5f$ electrons hybridize mostly to conduction electrons derived from $6p$ orbitals in UBi_2 , $5p$ in USb_2 , and $4p$ in UAs_2 ²². Due to the widest bandwidth originating from highly delocalized $6p$ orbitals in UBi_2 the relative ratio of hybridization to conduction electron bandwidth can be expected to be small. Consequently, by virtue of the same argument UAs_2 can be characterized with a relatively large effective hybridization in units of conduction bandwidth. Therefore, one can expect that small hybridization, which usually favors antiferromagnetic orderings even quite away from half filling in Anderson lattice^{39,40}, leads to antiferromagnetic order in both semi-independent subsystems in UBi_2 providing observed standard $\uparrow\downarrow\uparrow\downarrow$ ordering in contrast to a situation in USb_2 and UAs_2 .

B. UAsSe

UAsSe is a ferromagnet at ambient pressure²⁶. By comparing crystal structures of USb_2 with UAsSe , the arsenic and selenium atoms in the latter compound play the role of Sb(I) and Sb(II) atoms respectively in USb_2 . In turn, photoemission studies⁵³ suggest that the delocalization of $5f$ electrons is direction-dependent, i.e., f -states strongly contribute to the band dispersion within $x-y$ plane while have localized nature along z -axis. These properties of UAsSe support a formation of two semi-independent subsystems, weakly dispersive along z -axis, and thus coupled mostly through sharing single layer of uranium atoms in a same manner as we propose in a present work for USb_2 .

The emergence of uniform ferromagnetic polarization in UAsSe instead of non-standard antiferromagnetic ordering in USb_2 can be attributed to many potential reasons, though here we address only one. The emergent conduction electron bands derived from arsenic and selenium atoms in UAsSe can even more significantly differ in hybridization functions and relative shift Δ than it is the case for these derived from Sb(I) and Sb(II) atoms in USb_2 . Such circumstance may lead to the situation in which one of the subsystems is characterized with the filling sizably lower and the other sizably higher than half-filling. This may follow that ferromagnetism can be more stable against antiferromagnetism that is usually favored in the vicinity of half-filling. It must be noted however that a present theoretical approach is not well-suited to address UAsSe for its complete set of properties. Namely, the Kondo-signatures^{24,25} cannot be addressed within renormalized mean-field theory which treats quantum fluctuations in an oversimplified manner to account properly for this class of many-body effects.

C. URh_xIr_{1-x}Ge

URhGe is an itinerant ferromagnet that reflects unusual coexistence of uniform polarization with a spin-triplet superconductivity^{2,54}. There are evidences for a predominant mechanism for a delocalization of 5f electrons based on a hybridization to other orbitals in this material, presumably 4d of ruthenium⁵⁵. Although, the distance between neighboring uranium atoms is at the border of the so-called Hill-limit to unambiguously neglect direct f - f electron hopping, in a following we shall assume that effectively ferromagnetism in URhGe can be described by the Anderson lattice model (cf. Eq. (5)). In that manner the results of Fig. 2 derived for such a model may apply to the case of this material.

In a recent experiments there has been thoroughly examined evolution with doping of the magnetic ground-state of URhGe when rhodium is exchanged for iridium²⁷. At 56% content of Ir (URh_xIr_{1-x}Ge, $x = 0.56$) the compound undergoes transition to antiferromagnetic state with a very similar staggered and uniform magnetizations at both sides of a transition²⁷. Doping with iridium may gradually change the character of conduction states from 4d to 5d, and therefore to increase of their bandwidth. In result effective hybridization in a units of bandwidth should decrease, what according to results presented in Fig. 2(a) can rationalize magnetic ground state switch observed in URh_xIr_{1-x}Ge²⁷.

D. UGe₂

In the present work, the character of ferromagnetism in pressurized USb₂ is proposed to originate from the competition between $c-f$ hybridization and $f-f$ interaction energy scales within the framework of Anderson lattice model. Previously we have proposed²⁸⁻³⁰ the same mechanism for ferromagnetism in the spin-triplet superconductor UGe₂³¹. According to our present choice of parameters, high pressure ferromagnetic phase in USb₂ has a character similar to the strongly polarized phase (FM1) of UGe₂²⁸.

There exists a number of observations suggesting

that ferromagnetism and superconductivity in UGe₂ are strongly intertwined². It may follow that, the onset of superconductivity is related to the particular mechanism driving the ferromagnetic state itself. In result, advocated scenario of the same mechanism leading to appearance of ferromagnetism in pressurized USb₂ and in UGe₂, may hint that the former compound also develops triplet superconductivity in yet experimentally unexplored regime²¹ of temperature below 2K.

V. SUMMARY

In the present work we have developed low-energy model which at the mean-field level explains magnetic properties of USb₂: the unusual $\uparrow\downarrow\uparrow$ sequence of polarizations at uranium atoms along [001] crystallographic direction^{15,19} and the pressure induced transition to the ferromagnetic state²¹. Relying on the obtained results for the proposed model we have addressed some of the properties of magnetic states also in other U-based compounds: UAs₂ and UBi₂^{16,17,22,23}, UAsSe²⁴⁻²⁶ and URh_xIr_{1-x}Ge²⁷. Moreover, our modeling suggests a strong analogy between ferromagnetic phases of USb₂ and spin-triplet superconductor UGe₂^{28,29}. Finally, we note that the present work can guide future studies toward explanation of other intriguing observations available for USb₂ such as a presence of a kink in f -electron dispersion^{10,12} and T -linear scattering rate in the high-pressure paramagnetic phase²¹.

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